Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-366-1048

Inclosure Material:
Metal
Overall Length:
Between 4.625 inches and 5.625 inches
Overall Diameter:
1.047 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-30
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 reverse voltage, peak
Current Rating Per Characteristic:
150.00 amperes forward current, average
Power Rating Per Characteristic:
180.0 watts small-signal input power, common-collector absolute
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0